### **Silicon Bridge Rectifiers**



# KBP200 Thru 2010

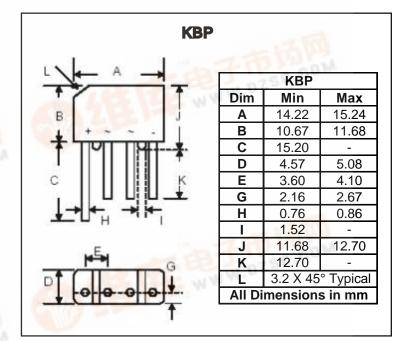
Reverse Voltage: 50 - 1000 Volts Forward Current: 2.0 Amp

#### Features

Diffused Junction Low Forward Voltage Drop High Current Capability High Reliability High Surge Current Capability Ideal for Printed Circuit Boards

#### Mechanical Data

Case: Molded Plastic Terminals: Plated Leads Solderable per MIL-STD-202, Method 208 Weight: 1.7 grams (approx.) Mounting Position: Any Marking: Type Number



### **Maximum Ratings and Electrical Characterics**

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

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CHARACTERISTICS	Symbol	KBP 200	KBP 201	KBP 202	KBP 204	KBP 206	KBP 208	KBP 2010	UNIT
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>	1	19 -						
Working Peak Reverse Voltage	V <sub>RWM</sub>	50	100	200	400	600	800	1000	V
DC Blocking Voltage	V <sub>R</sub>								
RMS Reverse Voltage	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Average Rectified Output Current @ $T_A = 50^{\circ}C$ (Note 1)		2.0							А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rate load (JEDEC Method)	I <sub>FSM</sub>	60 60 COM							А
Forward Voltage (per element) @I <sub>F</sub> = 2.0A	V <sub>FM</sub>	1.1							V
Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$	I <sub>RM</sub>	10 500							uA
Rating for Fusing (t<8.3ms)	l <sup>2</sup> t	15							A <sup>2</sup> s
Typical Junction Capacitance per element (Note 2)	Cj	25							рF
Typical Thermal Resistance (Note 3)	R <sub>JA</sub>	30							K/W
Operating and Storage Temperature Range	Tj, T <sub>STG</sub>	-55 to +160							°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

<sup>2</sup> Thermal resistance junction to ambient mounted on PC board with 12mm<sup>2</sup> copper pad.



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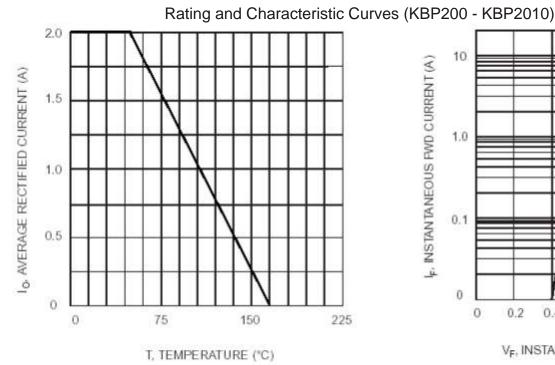


Fig. 1 Forward Current Derating Curve

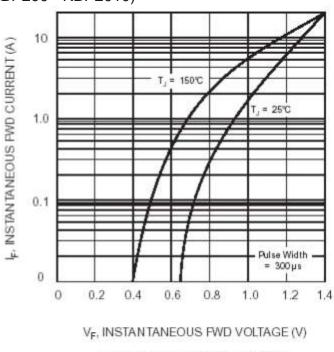
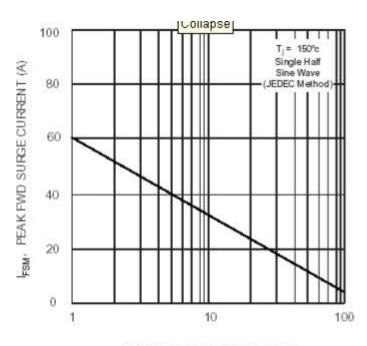
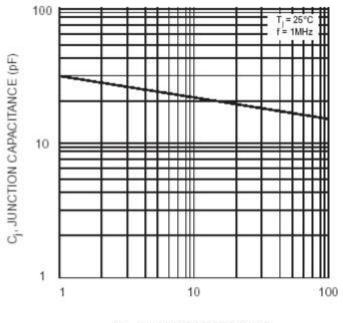


Fig. 2 Typical Fwd Characteristics

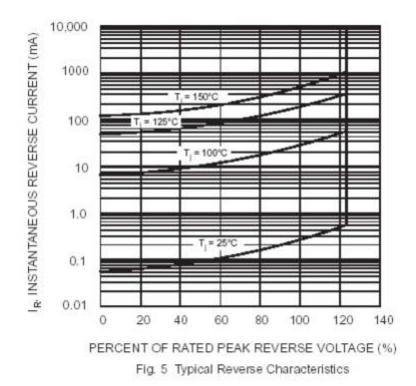






V<sub>R</sub>, REVERSE VOLTAGE (V) Fig. 4 Typical Junction Capacitance





Rating and Characteristic Curves (KBP200 - KBP2010)